

## **Switchmode Dual Fast Recovery Power Rectifiers**

... Designed for use in switching power supplies. inverters and as free wheeling diodes. These state-of-the-art devices have the following features:

- \* Glass Passivated chip junctions
- \* Low Reverse Leakage Current
- \* Fast Switching for High Efficiency
- \* 150 °C Operating Junction Temperature
- \* Low Forward Voltage , High Current Capability
  \* Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O

## **MAXIMUM RATINGS**

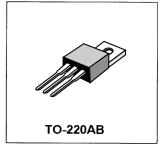
Characteristic	Symbol	Symbol			F16C		
		05	10	15	20		
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	50	100	150	200	V	
RMS Reverse Voltage	V <sub>R(RMS)</sub>	35	70	105	140	V	
Average Rectifier Forward Current Per Leg T <sub>c</sub> =125°C Per Total Device	<sub>F(AV)</sub>	8.0 16			А		
Peak Repetitive Forward Current (Rate V <sub>R</sub> , Square Wave, 20kHz, T <sub>c</sub> =125°C)	l <sub>FM</sub>	16			Α		
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware,single phase,60Hz)	  FSM	150			Α		
Operating and Storage Junction Temperature Range	T <sub>j</sub> , T <sub>stg</sub>	- 65 to + 150			°C		

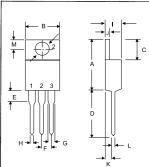
## **ELECTRICAL CHARACTERISTICS**

Characteristic	Symbol	F16C				Unit
		05	10	15	20	1
Maximum Instantaneous Forward Voltage ( $I_F$ =8.0 Amp, $T_c$ = 25 $^{\circ}$ C)	V <sub>F</sub>	1.30			V	
Maximum Instantaneous Reverse Current ( Rated DC Voltage, $T_c = 25$ °C) ( Rated DC Voltage, $T_c = 125$ °C)	I <sub>R</sub>	10 500			uA	
Reverse Recovery Time ( $I_F = 0.5 \text{ A}, I_R = 1.0, I_{rr} = 0.25 \text{ A}$ )	T <sub>rr</sub>	150			ns	
Typical Junction Capacitance ( Reverse Voltage of 4 volts & f=1 MHz)	C <sub>P</sub>	120			pF	

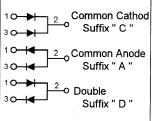
**FAST RECOVERY RECTIFIERS** 

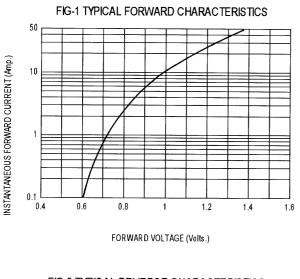
**16 AMPERES** 50 -- 200 VOLTS

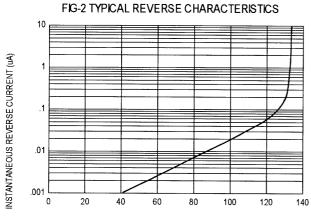


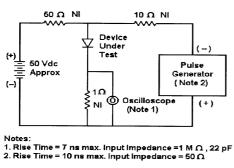


	MILLMETERS			
DIM	MIN	MAX		
Α	14.68	15.32		
В	9.78	10.42		
С	6.01	6.52		
D	13.06	14.62		
Ε	3.57	4.07		
F	2.42	2.66		
G	1.12	1.36		
Н	0.72	0.96		
- 1	4.22	4.98		
j	1.14	1.36		
K	2.20	2.97		
L	0.33	0.55		
М	2.48	2.98		
0	3.70	3.90		



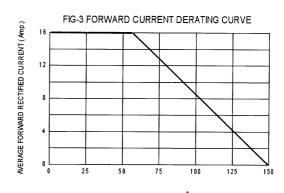


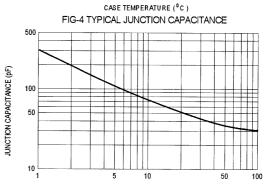


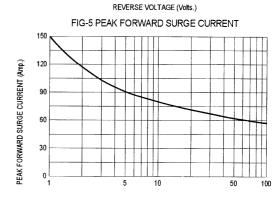


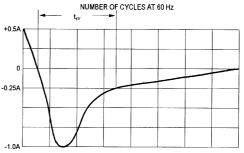
PERCENT OF PEAK REVERSE VOLTAGE(%)











Set time base for 50 ns/div

Fig-6 Reverse Recovery Time Characteristic and Test Circuit Diagram